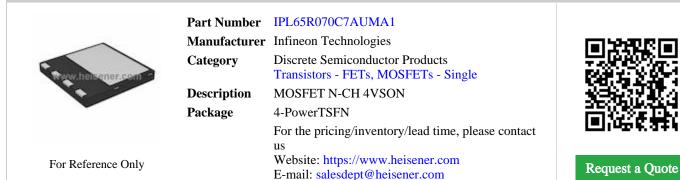


IPL65R070C7AUMA1

IPL65R070C7AUMA1 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPL65R070C7AUMA1 Specifications

Manufacturer Part Number	IPL65R070C7AUMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	4-PowerTSFN
Series	CoolMOS? C7
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	28A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 850µA
Gate Charge (Qg) (Max) @ Vgs	64nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3020pF @ 100V
Vgs (Max)	$\pm 20 \mathrm{V}$
FET Feature	-
Power Dissipation (Max)	169W (Tc)
Rds On (Max) @ Id, Vgs	70 mOhm @ 8.5A, 10V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-VSON-4
Package / Case	4-PowerTSFN
	Report errors?

IPL65R070C7AUMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPL65R070C7AUMA1 Payment Methods



If you have any question about IPL65R070C7AUMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com